



10-FZ074PA050SM-L624F08
10-PZ074PA050SM-L624F08Y
datasheet

Vincotech

fastPACK 0 H C		650 V / 50 A
Features		
	<ul style="list-style-type: none">• High speed H-Bridge• High efficiency IGBT H5• Full current fast FWD• Integrated capacitors• Thermistor	
Target applications		Schematic
	<ul style="list-style-type: none">• Power Supply• Solar Inverters• UPS• Welding & Cutting	
Types		
	<ul style="list-style-type: none">• 10-FZ074PA050SM-L624F08• 10-PZ074PA050SM-L624F08Y	

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
H-Bridge Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	41	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	150	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	78	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
H-Bridge Diode				
Peak repetitive reverse voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$	53	A
Repetitive peak forward current	I_{FRM}		100	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	76	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Capacitor (DC)

Maximum DC voltage	V_{MAX}		630	V
Operation Temperature	T_{op}		-55...+125	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{op}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage*	$t_p = 2 \text{ s}$	6000	V
		AC Voltage	$t_p = 1 \text{ min}$	2500	V
Creepage distance				min. 12,7	mm
Clearance		with solder pins / with press-fit pins		9,55 / 9,57	mm
Comparative Tracking Index	CTI			> 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max			

H-Bridge Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0005	25	3,3	4	4,7	V
Collector-emitter saturation voltage	V_{CEsat}		15		50	25 125		1,82 2,00	2,22	V
Collector-emitter cut-off current	I_{CES}		0	650		25			40	µA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	r_g						none			Ω
Input capacitance	C_{ies}	$f = 1 \text{ MHz}$	0	25	25	25	3000	50	11	pF
Output capacitance	C_{oes}									
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g									

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4 \text{ W/mK}$						1,22		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{goff} = 8 \Omega$ $R_{gon} = 8 \Omega$	-5 / 15	350	50	25		35		
Rise time	t_r					125		36		ns
						150		36		
Turn-off delay time	$t_{d(off)}$					25		9		
Fall time	t_f	$Q_{fFWD} = 1,8 \mu\text{C}$ $Q_{fFWD} = 3,3 \mu\text{C}$ $Q_{fFWD} = 3,8 \mu\text{C}$				125		11		mWs
Turn-on energy (per pulse)	E_{on}					150		11		
						25		97		
Fall time	t_f					125		109		
						150		117		
Turn-on energy (per pulse)	E_{on}					25		4		
						125		7		
Fall time	t_f					150		9		
Turn-off energy (per pulse)	E_{off}					25		1,028		
						125		1,159		
						150		1,278		
						25		0,238		
						125		0,394		
						150		0,437		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

H-Bridge Diode

Static

Forward voltage	V_F			50	25 125		1,50 1,44	1,77	V
Reverse leakage current	I_R		650		25			2,65	μA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	phase-change material $\lambda = 3,4 \text{ W/mK}$					1,26		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 4061 \text{ A}/\mu\text{s}$ $di/dt = 5418 \text{ A}/\mu\text{s}$ $di/dt = 3990 \text{ A}/\mu\text{s}$	-5 / 15	350	50	25		39		A
Reverse recovery time	t_{rr}					125		52		
						150		58		
Recovered charge	Q_r					25		86		
						125		109		
						150		121		ns
Recovered charge	Q_r	$di/dt = 4061 \text{ A}/\mu\text{s}$ $di/dt = 5418 \text{ A}/\mu\text{s}$ $di/dt = 3990 \text{ A}/\mu\text{s}$	-5 / 15	350	50	25		1,787		μC
Reverse recovered energy	E_{rec}					125		3,294		
						150		3,823		
Reverse recovered energy	E_{rec}					25		0,346		
						125		0,699		mWs
						150		0,831		
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$	$di/dt = 4061 \text{ A}/\mu\text{s}$ $di/dt = 5418 \text{ A}/\mu\text{s}$ $di/dt = 3990 \text{ A}/\mu\text{s}$	-5 / 15	350	50	25		301		
						125		451		
						150		472		
										$\text{A}/\mu\text{s}$

Capacitor (DC)

Capacitance	C						150		nF
Tolerance							-10		+10
Dissipation factor		$f = 1 \text{ kHz}$				25			2,5

Thermistor

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta R/R$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P					25		5		mW
Power dissipation constant						25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %				25		3962		K
B-value	$B_{(25/100)}$	Tol. ±1 %				25		4000		K
Vincotech NTC Reference								I		



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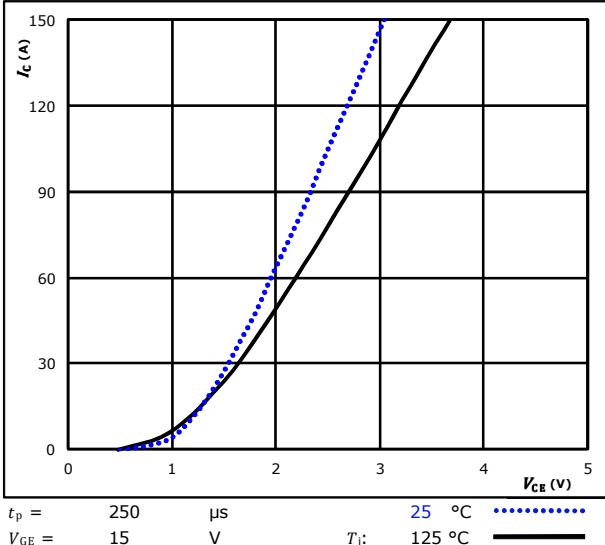
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H-Bridge Switch Characteristics

figure 1.

Typical output characteristics

$$I_C = f(V_{CE})$$

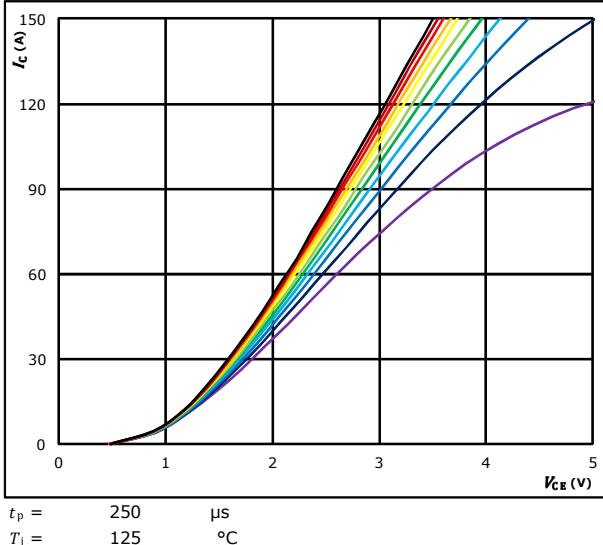


IGBT

figure 2.

Typical output characteristics

$$I_C = f(V_{CE})$$

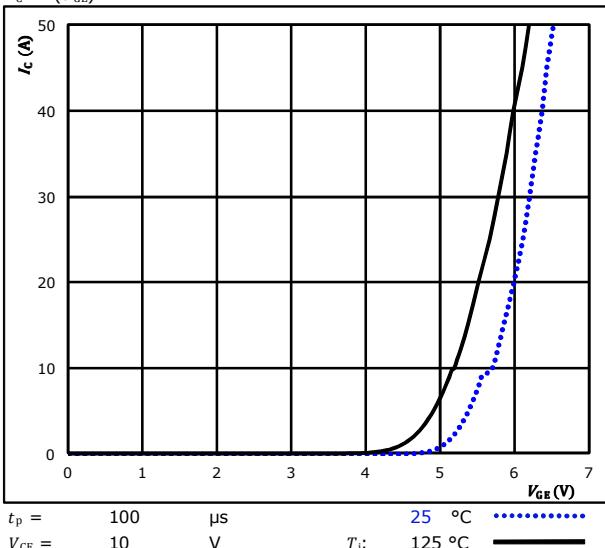


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figure 3.

Typical transfer characteristics

$$I_C = f(V_{GE})$$

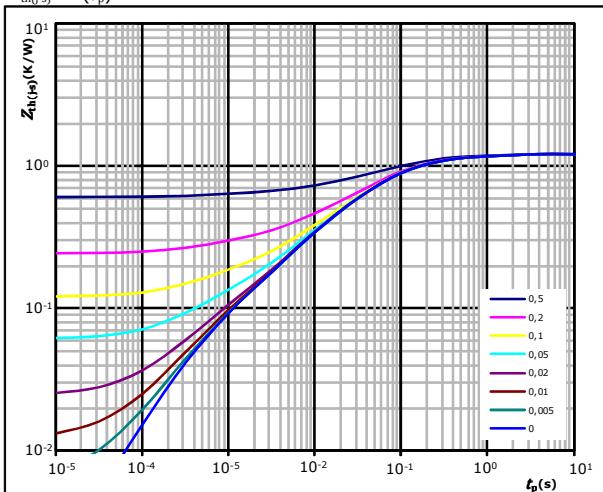


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figure 4.

Transient Thermal Impedance as function of Pulse duration

$$Z_{th(j-s)} = f(t_p)$$



IGBT thermal model values

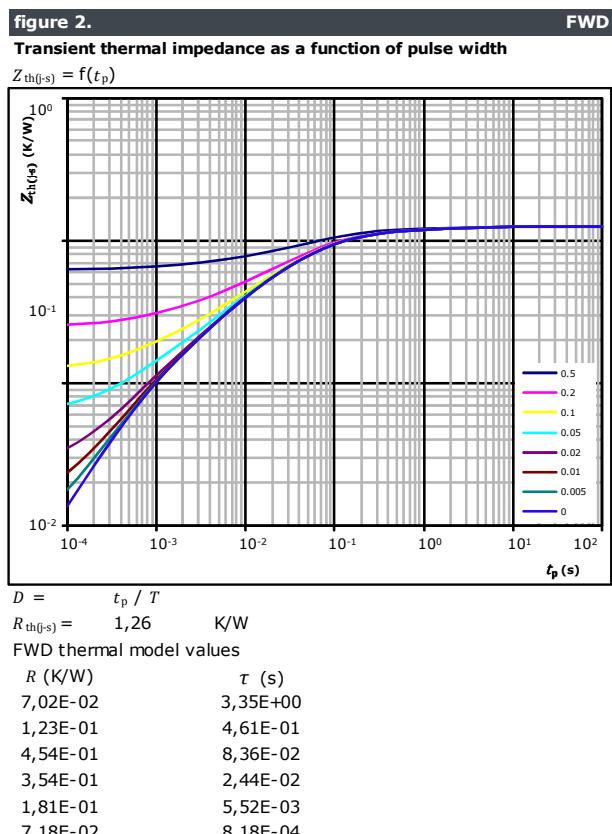
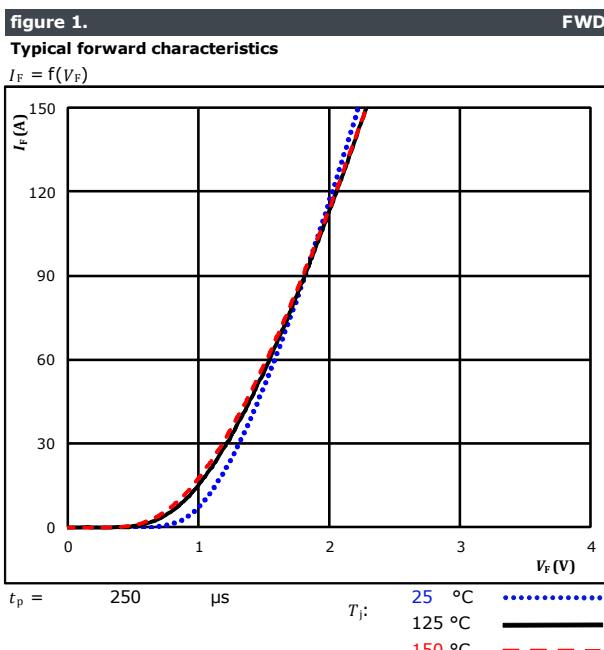
R (K/W)	τ (s)
4,40E-01	1,12E-01
3,96E-01	3,56E-02
1,75E-01	7,55E-03
3,44E-02	1,97E-03
4,80E-02	4,33E-04



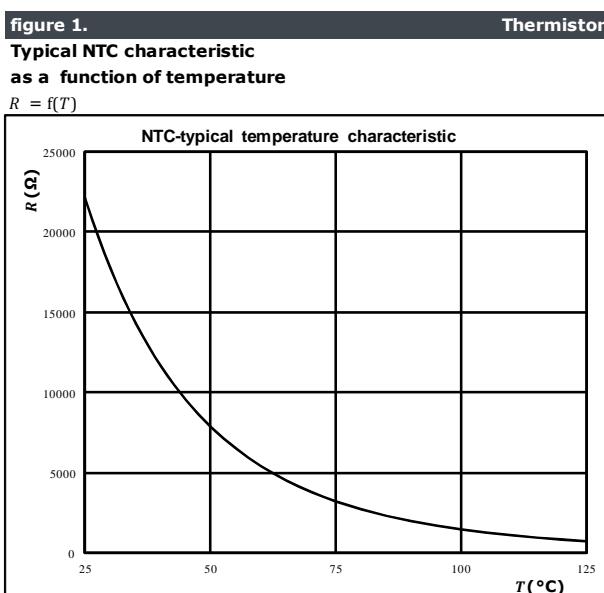
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H-Bridge Diode Characteristics



Thermistor Characteristics





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H-Bridge Switching Characteristics

figure 1.

Typical switching energy losses as a function of collector current

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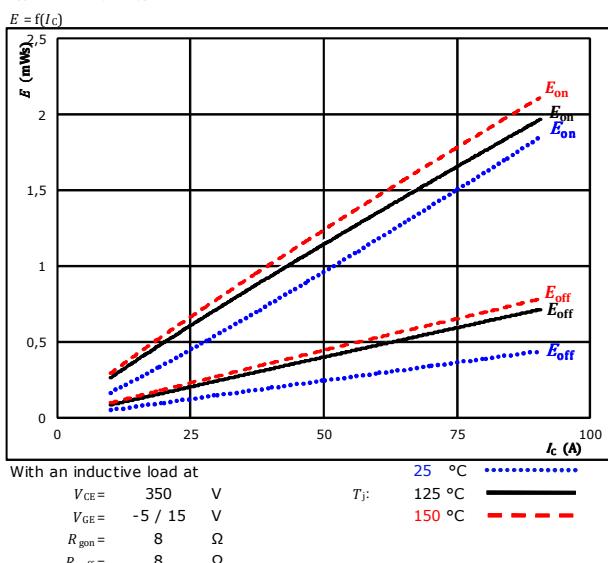


figure 2.

Typical switching energy losses as a function of gate resistor

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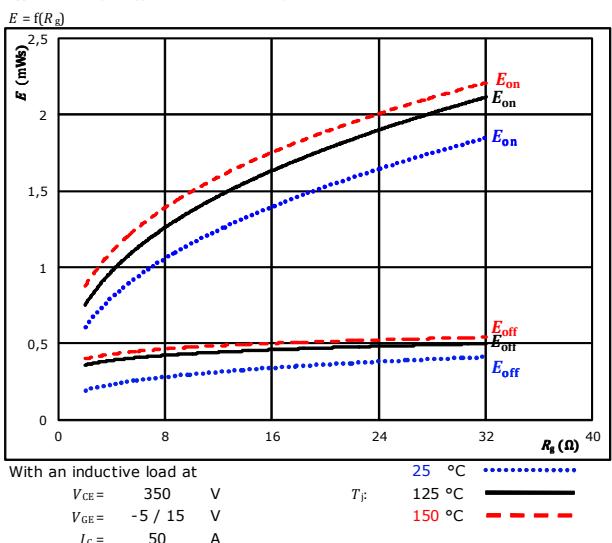


figure 3.

Typical reverse recovered energy loss as a function of collector current

FWD

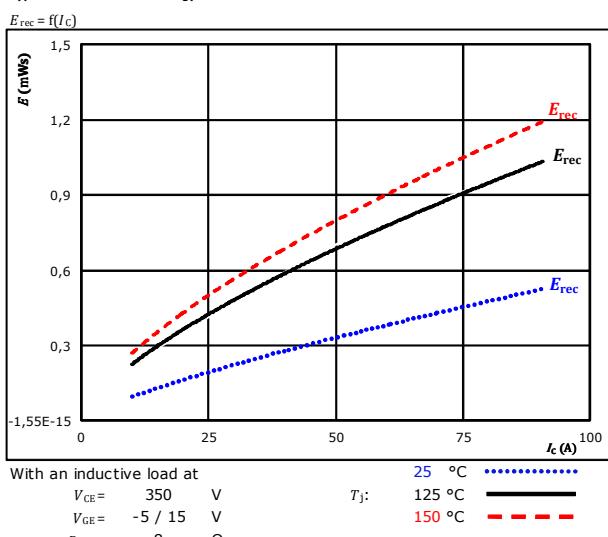
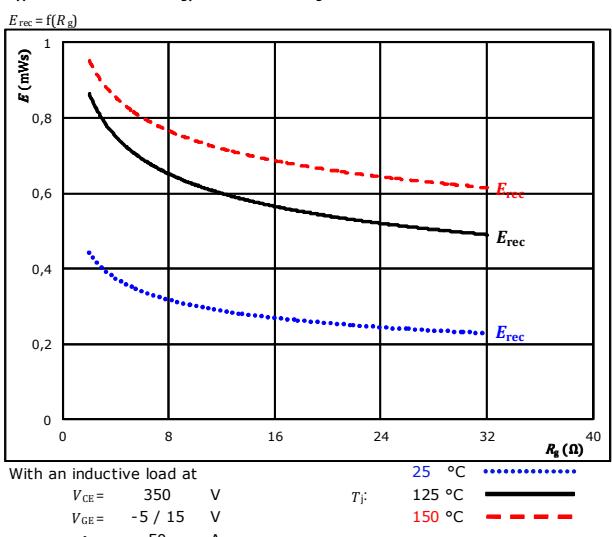


figure 4.

Typical reverse recovered energy loss as a function of gate resistor

FWD

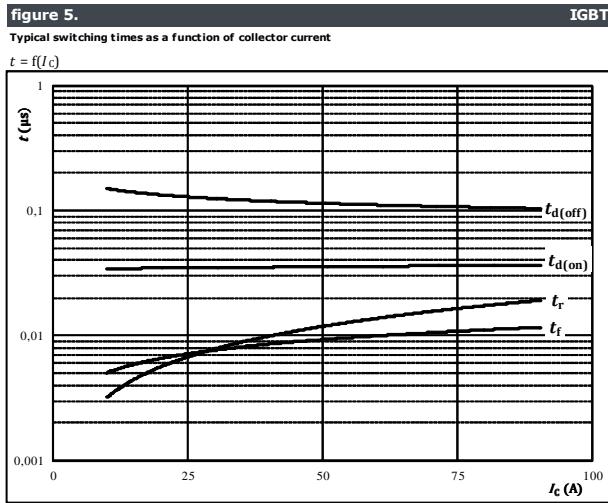




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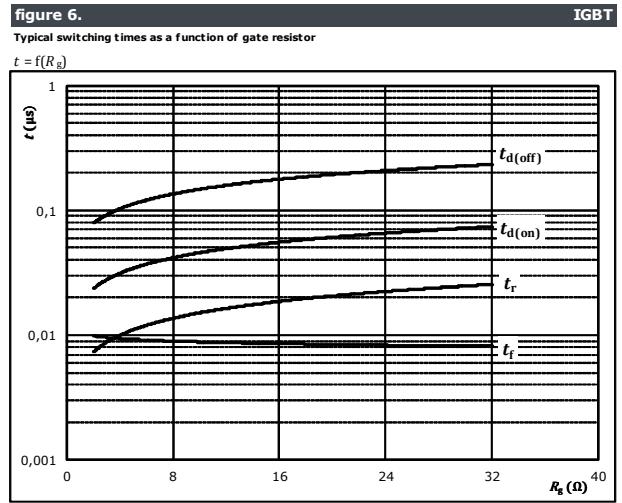
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H-Bridge Switching Characteristics



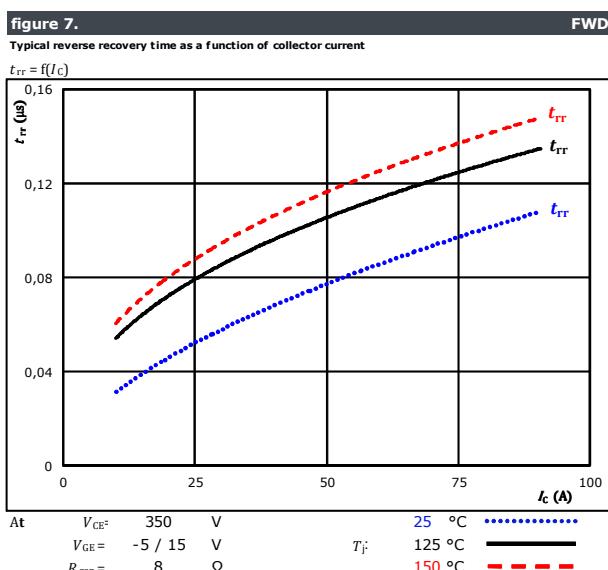
With an inductive load at

$T_J = 150^\circ\text{C}$
 $V_{CE} = 350\text{ V}$
 $V_{GE} = -5 / 15\text{ V}$
 $R_{gon} = 8\ \Omega$
 $R_{goff} = 8\ \Omega$

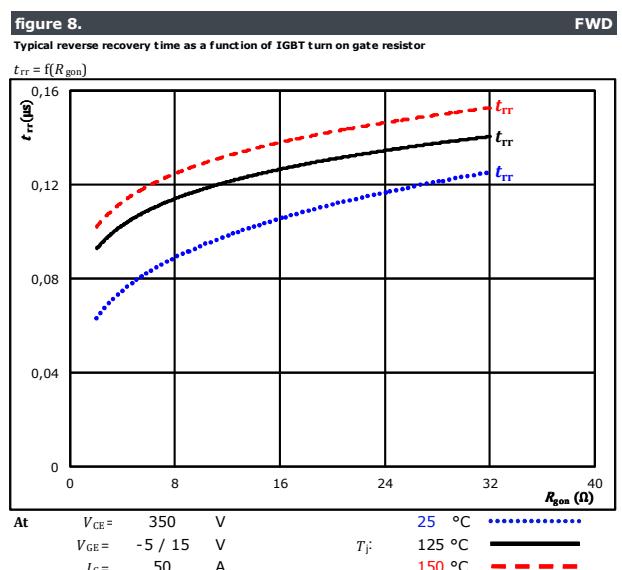


With an inductive load at

$T_J = 150^\circ\text{C}$
 $V_{CE} = 350\text{ V}$
 $V_{GE} = -5 / 15\text{ V}$
 $I_C = 50\text{ A}$



At $V_{CE} = 350\text{ V}$ $T_J = 25^\circ\text{C}$ $t_{rr} = 0.05\ \mu\text{s}$
 $V_{GE} = -5 / 15\text{ V}$ $T_J = 125^\circ\text{C}$ $t_{rr} = 0.08\ \mu\text{s}$
 $R_{gon} = 8\ \Omega$ $T_J = 150^\circ\text{C}$ $t_{rr} = 0.06\ \mu\text{s}$



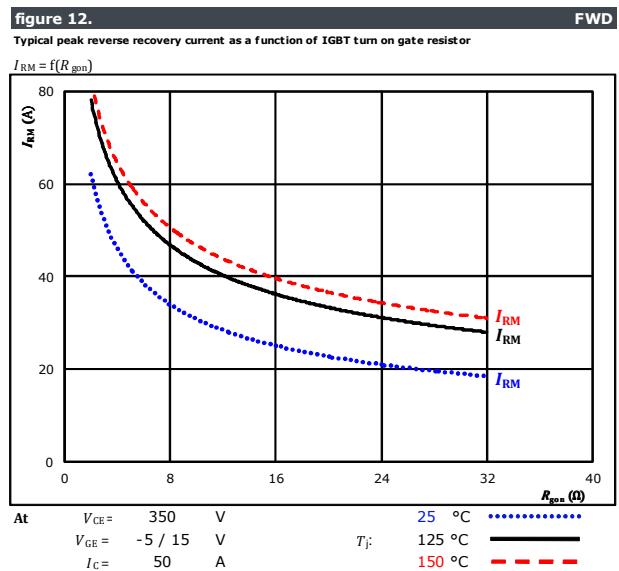
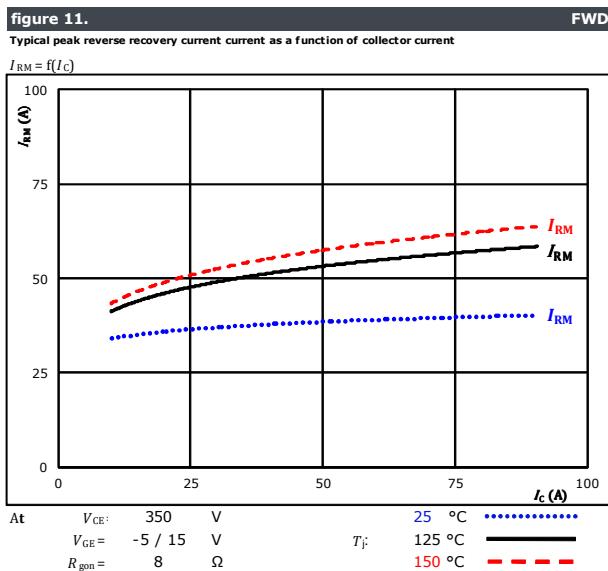
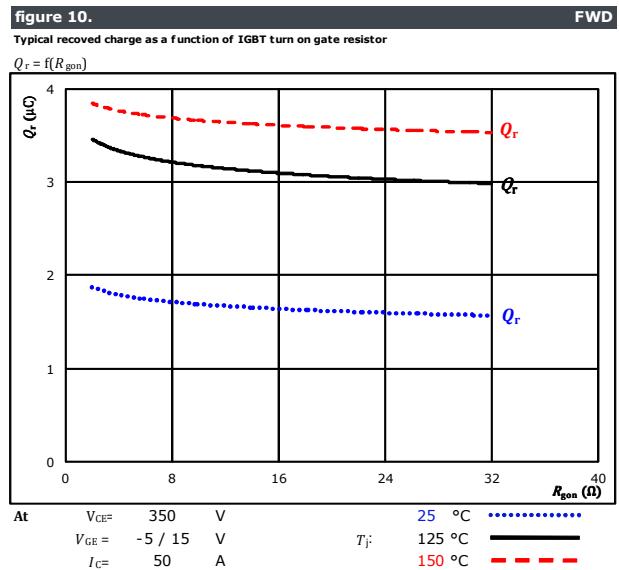
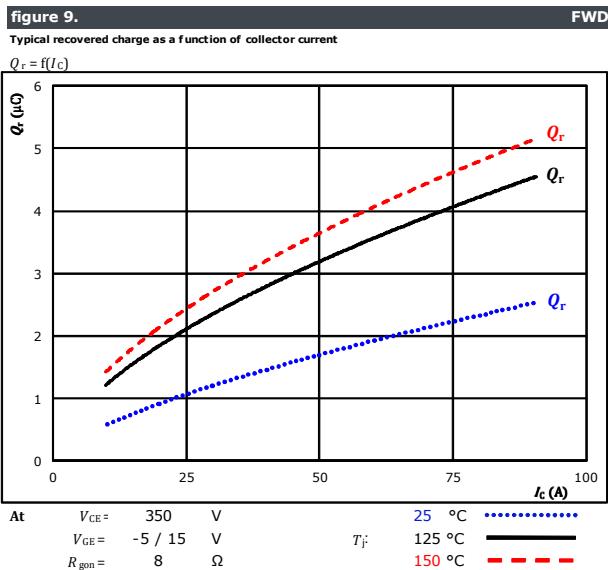
At $V_{CE} = 350\text{ V}$ $T_J = 25^\circ\text{C}$ $t_{rr} = 0.08\ \mu\text{s}$
 $V_{GE} = -5 / 15\text{ V}$ $T_J = 125^\circ\text{C}$ $t_{rr} = 0.13\ \mu\text{s}$
 $I_C = 50\text{ A}$ $T_J = 150^\circ\text{C}$ $t_{rr} = 0.10\ \mu\text{s}$



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H-Bridge Switching Characteristics





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H-Bridge Switching Characteristics

figure 13.

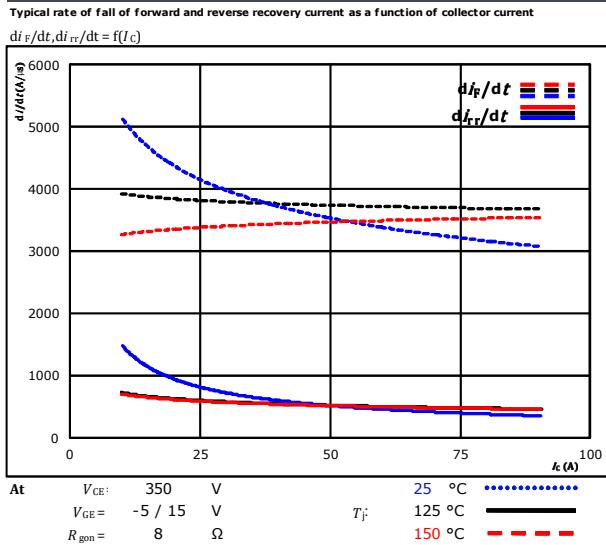


figure 14.

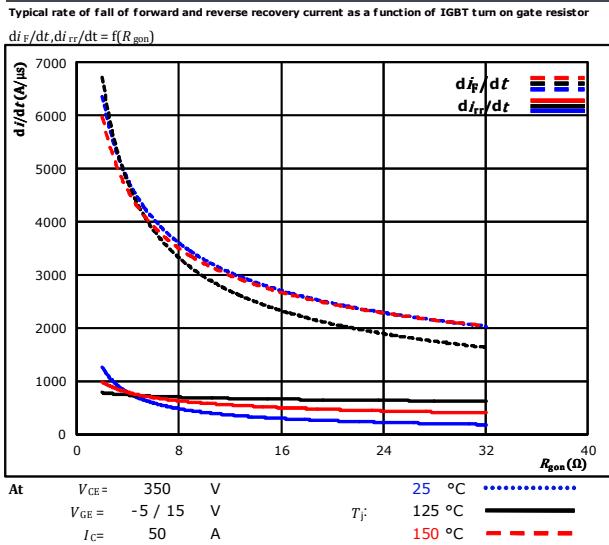
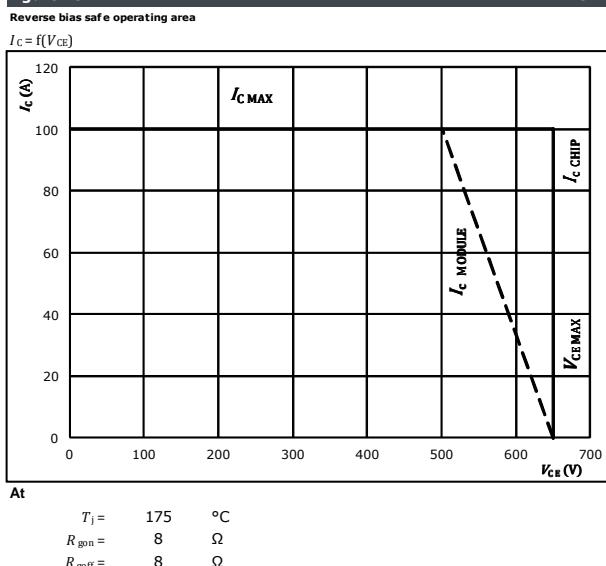


figure 15.





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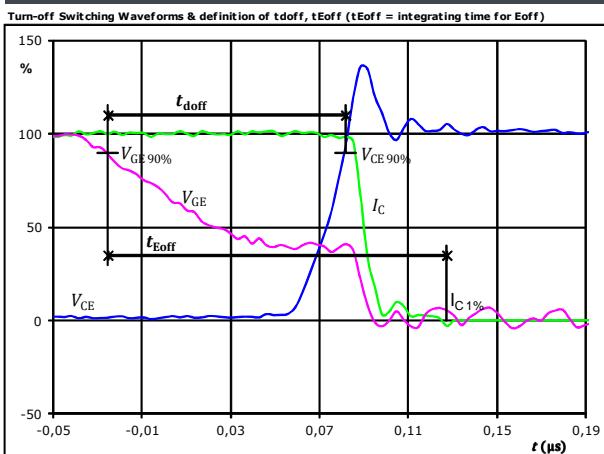
H-Bridge Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	8 Ω
R_{goff}	=	8 Ω

figure 1.

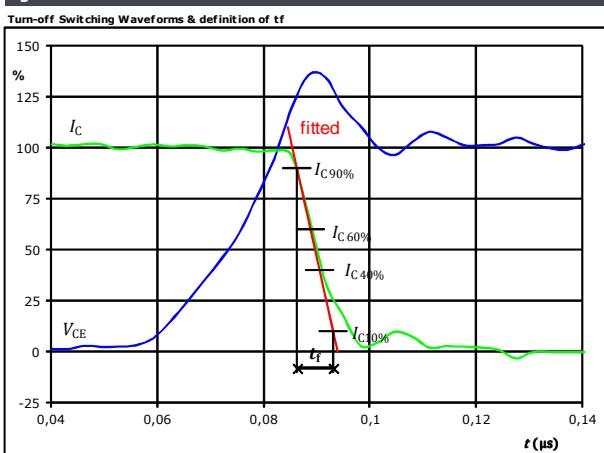
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$V_{GE}(0\%) =$	-5	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	350	V
$I_C(100\%) =$	50	A
$t_{doff} =$	0,109	μs
$t_{Eoff} =$	0,152	μs

figure 3.

IGBT

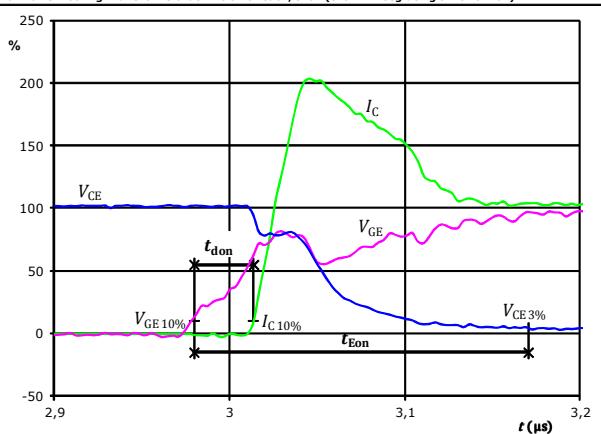


$V_C(100\%) =$	350	V
$I_C(100\%) =$	50	A
$t_f =$	0,007	μs

figure 2.

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Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

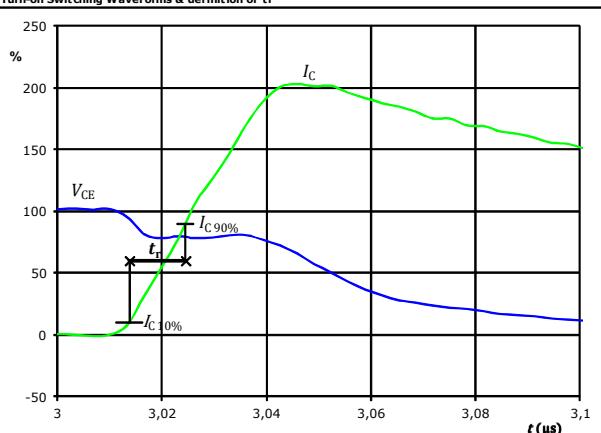


$V_{GE}(0\%) =$	-5	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	350	V
$I_C(100\%) =$	50	A
$t_{don} =$	0,036	μs
$t_{Eon} =$	0,191	μs

figure 4.

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Turn-on Switching Waveforms & definition of t_r



$V_C(100\%) =$	350	V
$I_C(100\%) =$	50	A
$t_r =$	0,011	μs



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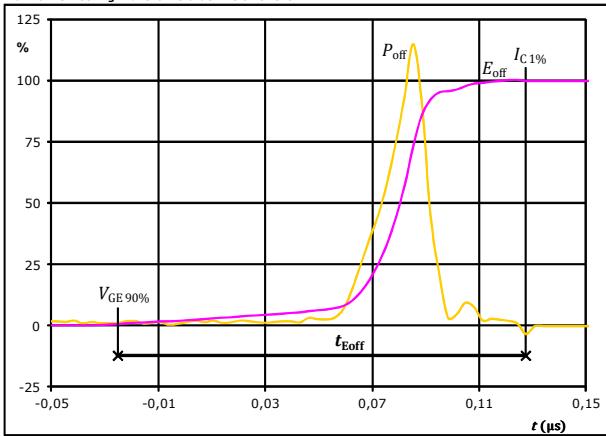
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H-Bridge Switching Characteristics

figure 5.

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Turn-off Switching Waveforms & definition of t_{Eoff}

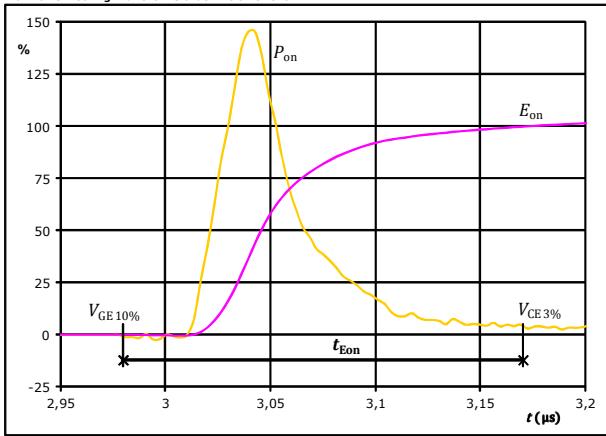


$P_{off}(100\%) = 17,40 \text{ kW}$
 $E_{off}(100\%) = 0,39 \text{ mJ}$
 $t_{Eoff} = 0,15 \mu s$

figure 6.

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Turn-on Switching Waveforms & definition of t_{Eon}

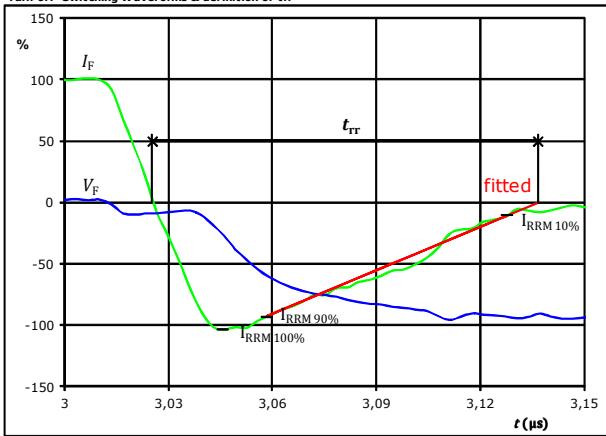


$P_{on}(100\%) = 17,40 \text{ kW}$
 $E_{on}(100\%) = 1,16 \text{ mJ}$
 $t_{Eon} = 0,19 \mu s$

figure 7.

FWD

Turn-off Switching Waveforms & definition of t_{rr}



$V_F(100\%) = 350 \text{ V}$
 $I_F(100\%) = 50 \text{ A}$
 $I_{RRM}(100\%) = -52 \text{ A}$
 $t_{rr} = 0,109 \mu s$



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H-Bridge Switching Characteristics

figure 8.

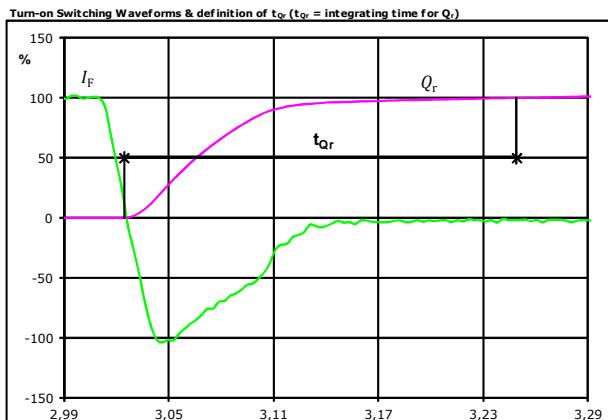
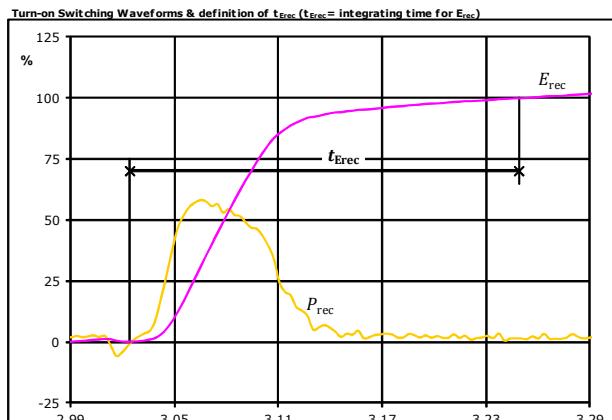


figure 9.





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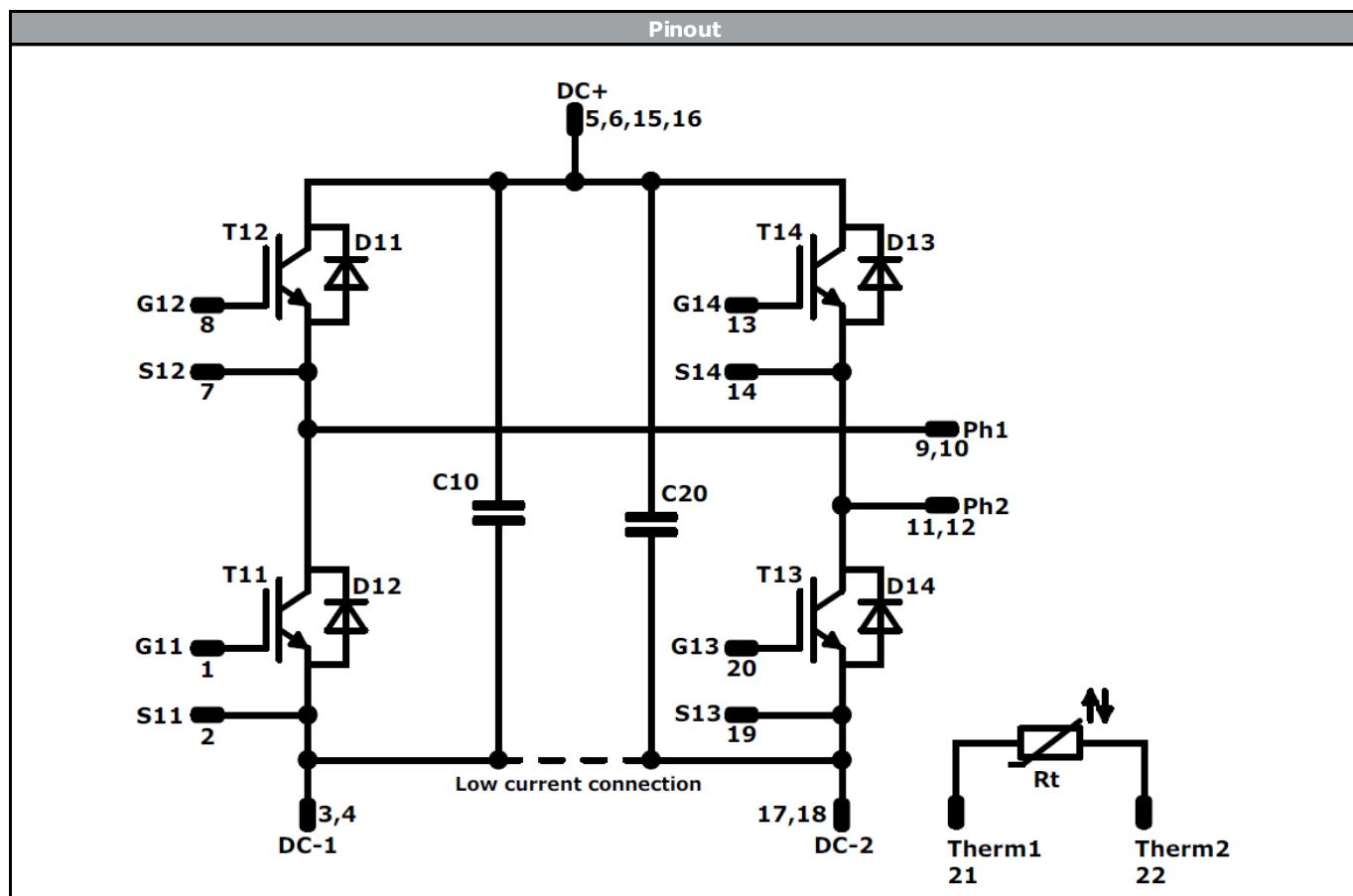
Ordering Code & Marking							
Version				Ordering Code			
without thermal paste with solder pins 12 mm housing				10-FZ074PA050SM-L624F08			
without thermal paste with press-fit pins 12 mm housing				10-PZ074PA050SM-L624F08Y			
NN-NNNNNNNNNNNNNN TTTTTTVVWWYY UL VIN LLLLL SSSS			Text	Name NN-NNNNNNNNNNNN-TTTTTV	Date code WWYY	UL & VIN UL VIN	Lot LLLLL
		Datamatrix	Type&Ver TTTTTTVV	Lot number LLLLL	Serial SSSS	Date code WWYY	Serial SSSS

Outline																																																																																																			
Pin table [mm]				Outline																																																																																															
<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>0</td><td>22,5</td><td>G11</td></tr><tr><td>2</td><td>2,9</td><td>22,5</td><td>S11</td></tr><tr><td>3</td><td>8,3</td><td>22,5</td><td>DC-1</td></tr><tr><td>4</td><td>10,8</td><td>22,5</td><td>DC-1</td></tr><tr><td>5</td><td>19,6</td><td>22,5</td><td>DC+</td></tr><tr><td>6</td><td>22,1</td><td>22,5</td><td>DC+</td></tr><tr><td>7</td><td>29,1</td><td>22,5</td><td>S12</td></tr><tr><td>8</td><td>32</td><td>22,5</td><td>G12</td></tr><tr><td>9</td><td>33,5</td><td>17,8</td><td>Ph1</td></tr><tr><td>10</td><td>33,5</td><td>15,3</td><td>Ph1</td></tr><tr><td>11</td><td>33,5</td><td>7,2</td><td>Ph2</td></tr><tr><td>12</td><td>33,5</td><td>4,7</td><td>Ph2</td></tr><tr><td>13</td><td>32</td><td>0</td><td>G14</td></tr><tr><td>14</td><td>29,1</td><td>0</td><td>S14</td></tr><tr><td>15</td><td>22,1</td><td>0</td><td>DC+</td></tr><tr><td>16</td><td>19,6</td><td>0</td><td>DC+</td></tr><tr><td>17</td><td>10,8</td><td>0</td><td>DC-2</td></tr><tr><td>18</td><td>8,3</td><td>0</td><td>DC-2</td></tr><tr><td>19</td><td>2,9</td><td>0</td><td>S13</td></tr><tr><td>20</td><td>0</td><td>0</td><td>G13</td></tr><tr><td>21</td><td>0</td><td>8</td><td>Therm1</td></tr><tr><td>22</td><td>0</td><td>14,5</td><td>Therm2</td></tr></tbody></table>				Pin	X	Y	Function	1	0	22,5	G11	2	2,9	22,5	S11	3	8,3	22,5	DC-1	4	10,8	22,5	DC-1	5	19,6	22,5	DC+	6	22,1	22,5	DC+	7	29,1	22,5	S12	8	32	22,5	G12	9	33,5	17,8	Ph1	10	33,5	15,3	Ph1	11	33,5	7,2	Ph2	12	33,5	4,7	Ph2	13	32	0	G14	14	29,1	0	S14	15	22,1	0	DC+	16	19,6	0	DC+	17	10,8	0	DC-2	18	8,3	0	DC-2	19	2,9	0	S13	20	0	0	G13	21	0	8	Therm1	22	0	14,5	Therm2				
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10-FZ074PA050SM-L624F08
10-PZ074PA050SM-L624F08Y
datasheet

Vincotech



Identification					
ID	Component	Voltage	Current	Function	Comment
T11-T14	IGBT	650 V	50 A	H-Bridge Switch	
D11-D14	FWD	650 V	50 A	H-Bridge Diode	
C10, C20	Capacitor	630 V		Capacitor (DC)	
Rt	Thermistor			Thermistor	



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10-PZ074PA050SM-L624F08Y**
datasheet

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Packaging instruction			
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 0 packages see vincotech.com website.			

Package data			
Package data for flow 0 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-xZ074PA050SM-L624F08x-D1-14	30 May. 2017		

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